20V P-CHANNEL ENHANCEMENT MODE MOSFET

Product Summary

BV_{DSS}	$R_{DS(ON)}$ MAX	I_D MAX @ T_A = +25°C
-20V	495mΩ @ V_{GS} = -4.5V	-0.77A
	690mΩ @ V_{GS} = -2.5V	-0.67A
	960mΩ @ V_{GS} = -1.8V	-0.57A

Description and Applications

This MOSFET is designed to minimize the on-state resistance ($R_{DS(ON)}$), yet maintain superior switching performance, making it ideal for high efficiency power management applications.

- Portable Electronics

Features and Benefits

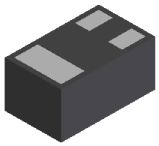
- Footprint of just 0.6mm^2 – 13 Times Smaller than SOT23
- 0.4mm Profile – Ideal for Low Profile Applications
- Low Gate Threshold Voltage
- Fast Switching Speed
- ESD Protected Gate
- **Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)**
- **Halogen and Antimony Free. "Green" Device (Note 3)**
- **For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please contact us or your local Diodes representative. https://www.diodes.com/quality/product-definitions/**

Mechanical Data

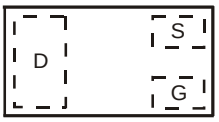
- Case: X2-DFN1006-3
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish – NiPdAu over Copper Leadframe. Solderable per MIL-STD-202, Method 208 e4
- Weight: 0.001 grams (Approximate)



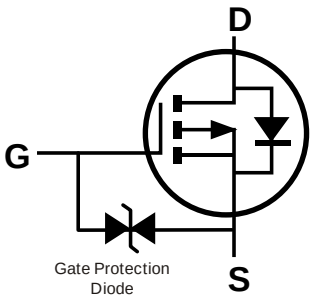
X2-DFN1006-3



Bottom View



Top View
Internal Schematic



Equivalent Circuit

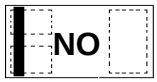
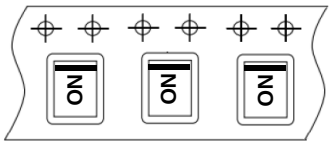
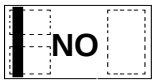
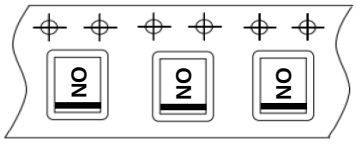
Ordering Information (Note 4)

Part Number	Marking	Reel Size (inches)	Tape Width (mm)	Tape Pitch (mm)	Quantity per Reel
DMP21D0UFB4-7R	NO	7	8	4	3,000
DMP21D0UFB4-7B	NO	7	8	2	10,000

Notes:
1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

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Marking Information

DMP21D0UFB4-7R	 Top View Bar Denotes Gate and Source Side 	NO = Part Marking Code
DMP21D0UFB4-7B	 Top View Bar Denotes Gate and Source Side 	NO = Part Marking Code

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Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic			Symbol	Value	Unit
Drain-Source Voltage			V_{DSS}	-20	V
Gate-Source Voltage			V_{GSS}	±8	V
Continuous Drain Current	Steady State	T_A = +25°C (Note 5)	I_D	-0.77	A
		T_A = +85°C (Note 5)		-0.55	
		T_A = +25°C (Note 6)		-1.17	
Pulsed Drain Current (Note 7)			I_{DM}	-5.0	A

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Power Dissipation (Note 5)	P_D	0.43	W
Power Dissipation (Note 6)	P_D	0.99	W
Thermal Resistance, Junction to Ambient (Note 5)	$R_{\theta JA}$	293	°C/W
Thermal Resistance, Junction to Ambient (Note 6)	$R_{\theta JA}$	126	°C/W
Operating and Storage Temperature Range	T_J, T_{STG}	-55 to +150	°C

Notes: 5. Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.
6. Device mounted on FR-4 substrate PC board, 2oz copper, with thermal vias to bottom layer 1inch square copper plate.
7. Device mounted on minimum recommended pad layout test board, 10μs pulse duty cycle = 1%.

Thermal Characteristics

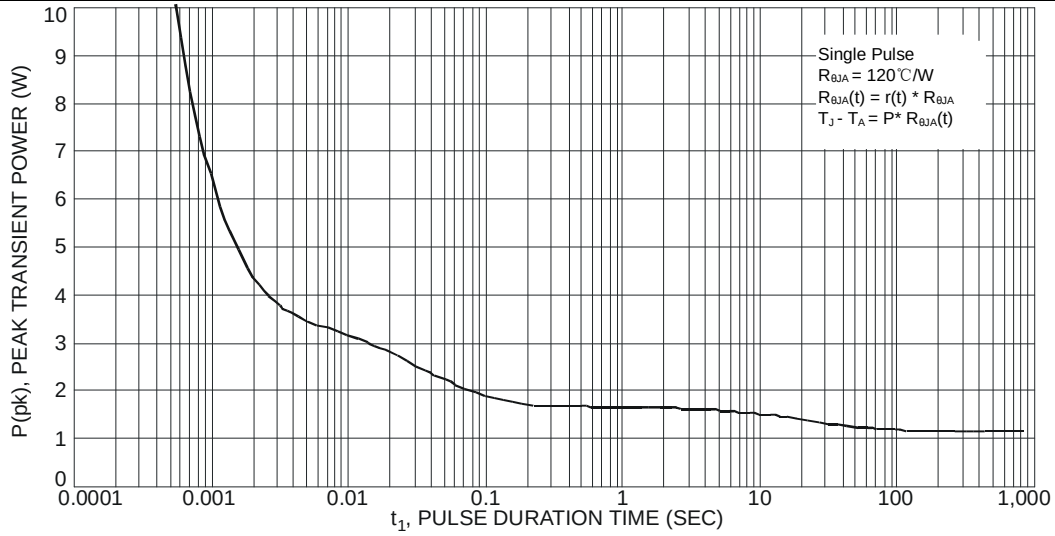


Fig. 1 Single Pulse Maximum Power Dissipation

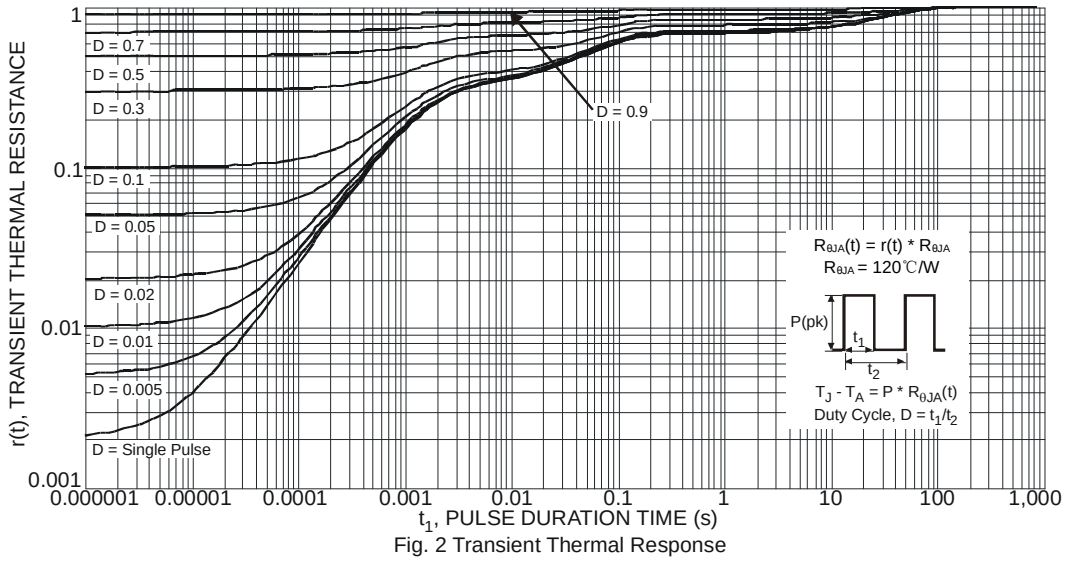


Fig. 2 Transient Thermal Response

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Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 8)						
Drain-Source Breakdown Voltage	BV_{DSS}	-20	—	—	V	V_{GS} = 0V, I_D = -250µA
Zero Gate Voltage Drain Current T_J = +25°C	I_{DSS}	—	—	-1	µA	V_{DS} = -20V, V_{GS} = 0V
Gate-Source Leakage	I_{GSS}	—	—	±10	µA	V_{GS} = ±8V, V_{DS} = 0V
ON CHARACTERISTICS (Note 8)						
Gate Threshold Voltage	$V_{GS(TH)}$	-0.5	-0.7	-1.0	V	V_{DS} = V_{GS}, I_D = -250µA
Static Drain-Source On-Resistance	$R_{DS(ON)}$	—	—	495	mΩ	V_{GS} = -4.5V, I_D = -400mA
				690		V_{GS} = -2.5V, I_D = -300mA
				960		V_{GS} = -1.8V, I_D = -100mA
Forward Transfer Admittance	$\|Y_{FS}\|$	50	—	—	ms	V_{DS} = -3V, I_D = -300mA
Diode Forward Voltage	V_{SD}	—	—	-1.2	V	V_{GS} = 0V, I_S = -300mA
DYNAMIC CHARACTERISTICS (Note 9)						
Input Capacitance	C_{iss}	—	76.5	—	pF	V_{DS} = -10V, V_{GS} = 0V, f = 1.0MHz
Output Capacitance	C_{oss}	—	13.7	—	pF	
Reverse Transfer Capacitance	C_{rss}	—	10.7	—	pF	
Gate Resistance	R_g	—	195	—	Ω	V_{DS} = 0V, V_{GS} = 0V, f = 1MHz
Total Gate Charge	Q_g	—	1.5	—	nC	V_{GS} = -8V, V_{DS} = -15V, I_D = -1A
Total Gate Charge	Q_g	—	1.0	—	nC	V_{GS} = -4.5V, V_{DS} = -15V, I_D = -1A
Gate-Source Charge	Q_{gs}	—	0.2	—	nC	
Gate-Drain Charge	Q_{gd}	—	0.3	—	nC	
Turn-On Delay Time	$t_{D(ON)}$	—	7.1	—	ns	V_{DS} = -10V, $-I_D$ = 1A, V_{GS} = -4.5V, R_g = 6Ω
Turn-On Rise Time	t_R	—	8.0	—	ns	
Turn-Off Delay Time	$t_{D(OFF)}$	—	31.7	—	ns	
Turn-Off Fall Time	t_F	—	18.5	—	ns	

Notes: 8. Short duration pulse test used to minimize self-heating effect.
9. Guaranteed by design. Not subject to product testing.

Typical Characteristics

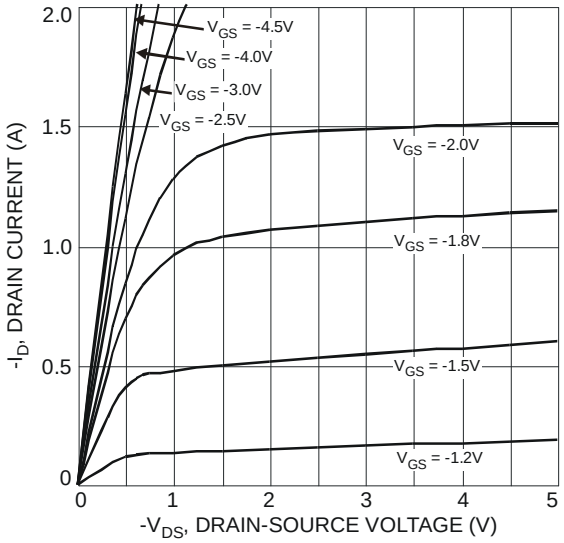


Fig. 3 Typical Output Characteristic

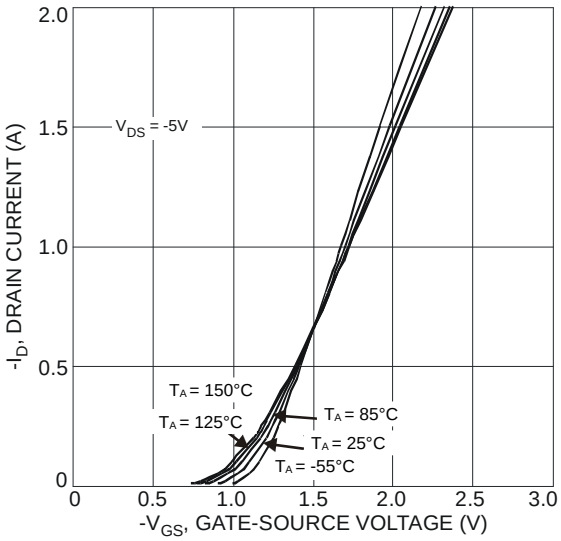


Fig. 4 Typical Transfer Characteristic

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Typical Characteristics (continued)

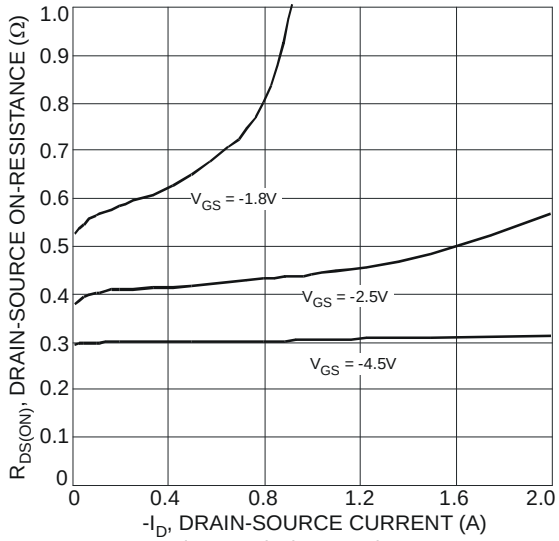


Fig. 5 Typical On-Resistance
vs. Drain Current and Gate Voltage

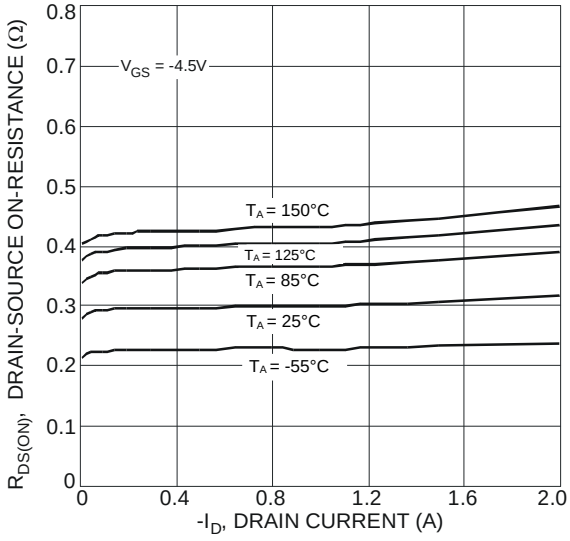


Fig. 6 Typical On-Resistance
vs. Drain Current and Temperature

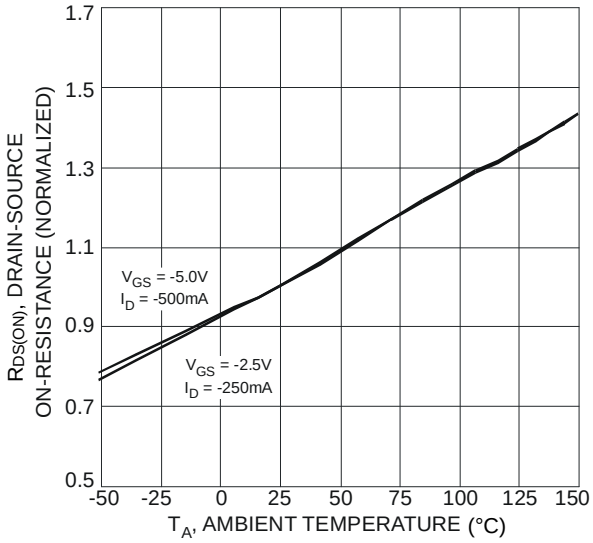


Fig. 7 On-Resistance Variation with Temperature

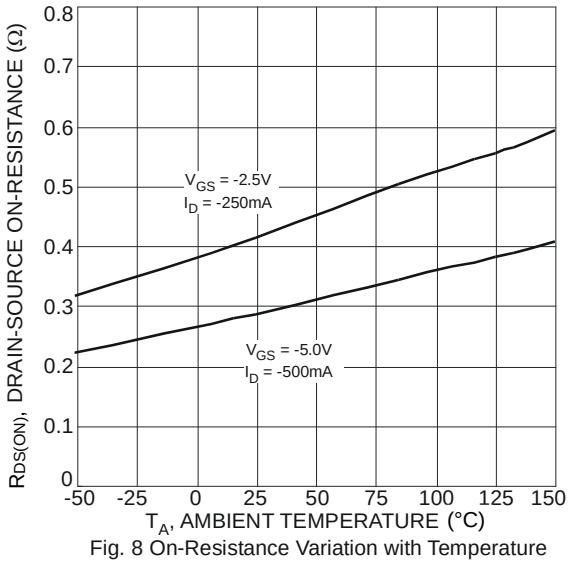


Fig. 8 On-Resistance Variation with Temperature

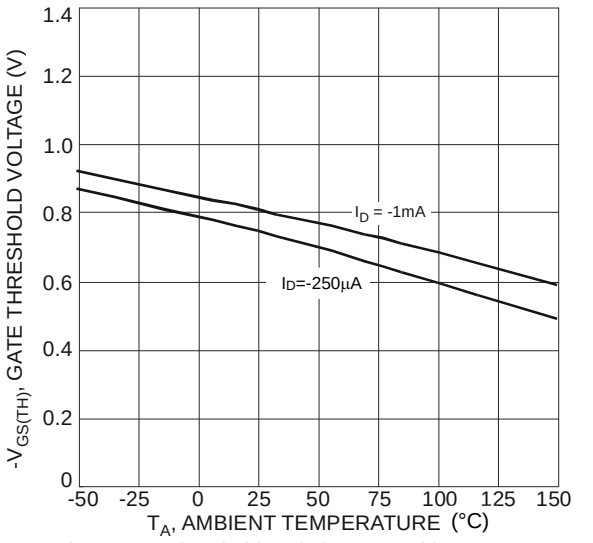


Fig. 9 Gate Threshold Variation vs. Ambient Temperature

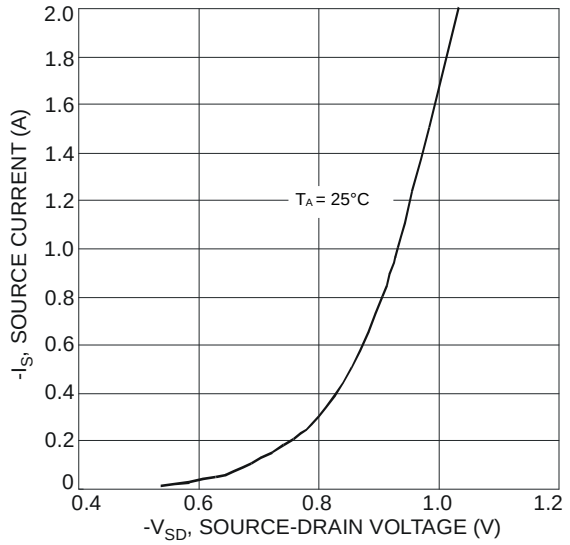


Fig. 10 Diode Forward Voltage vs. Current

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Typical Characteristics (continued)

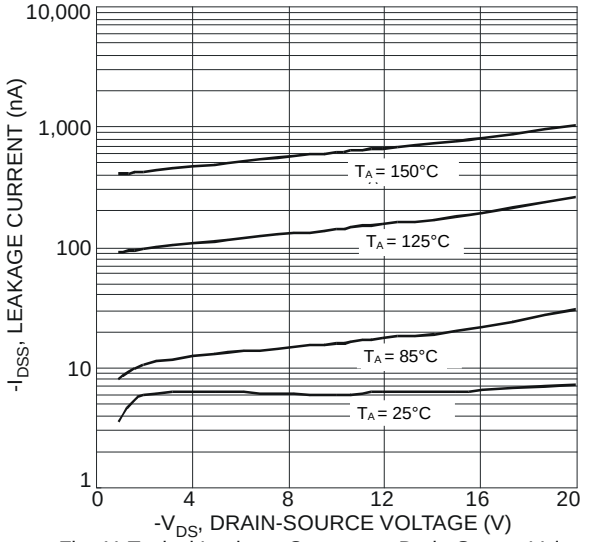


Fig. 11 Typical Leakage Current vs. Drain-Source Voltage

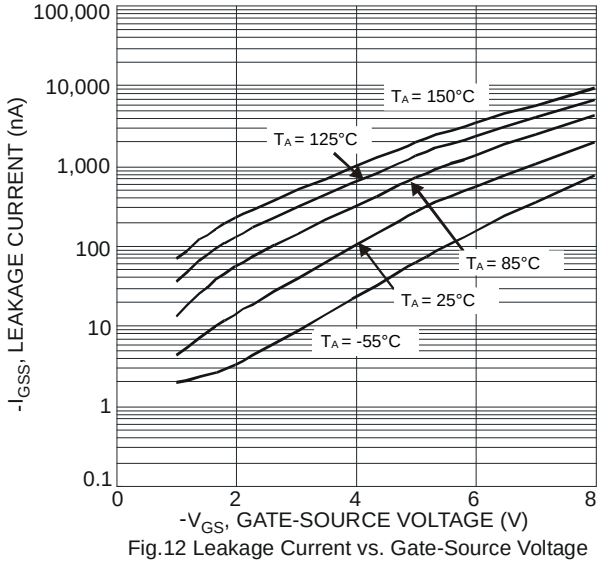


Fig.12 Leakage Current vs. Gate-Source Voltage

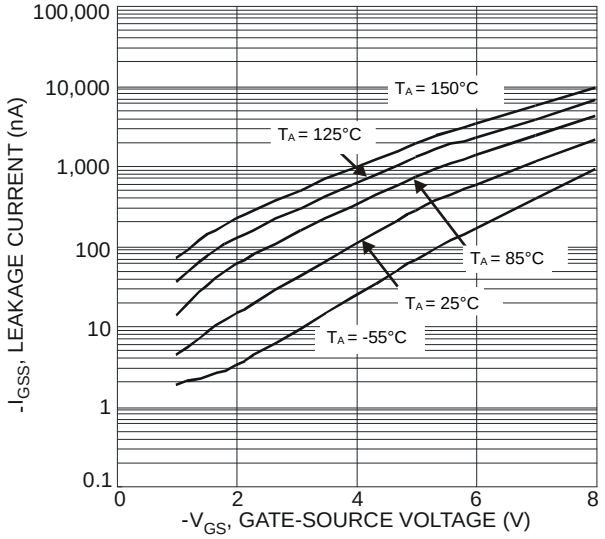


Fig.13 Leakage Current vs. Gate-Source Voltage

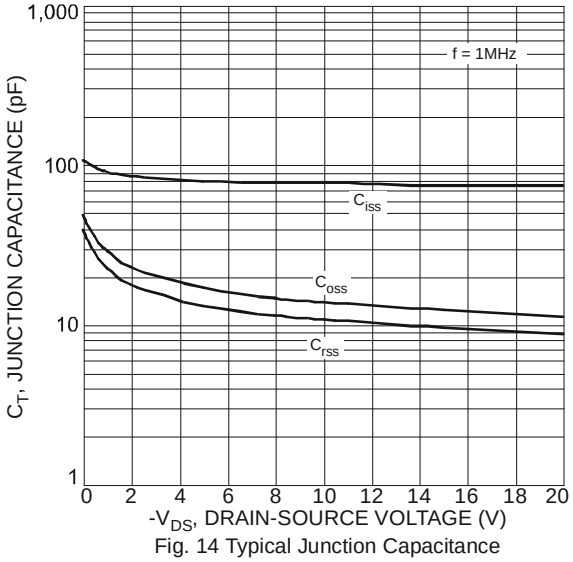


Fig. 14 Typical Junction Capacitance

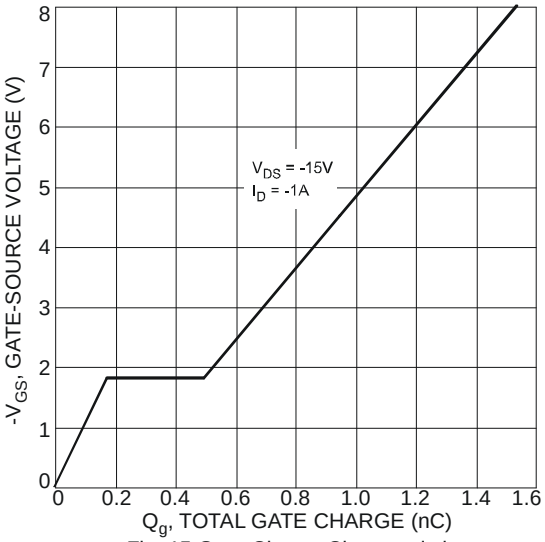


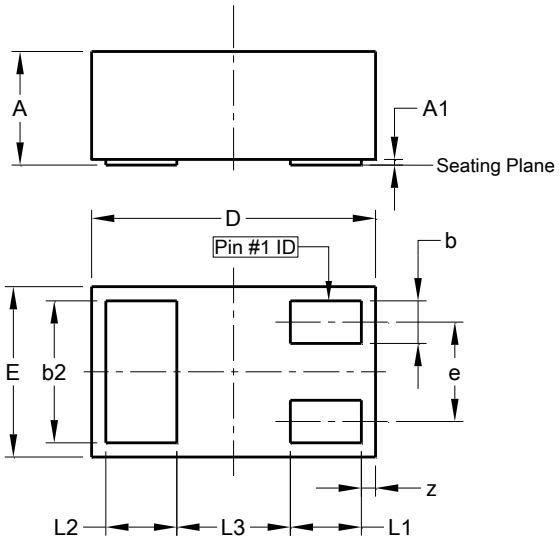
Fig. 15 Gate-Charge Characteristics

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Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

X2-DFN1006-3

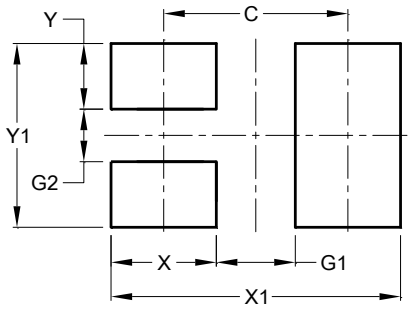


X2-DFN1006-3			
Dim	**Min**	**Max**	**Typ**
A	—	0.40	—
A1	0.00	0.05	0.03
b	0.10	0.20	0.15
b2	0.45	0.55	0.50
D	0.95	1.05	1.00
E	0.55	0.65	0.60
e	—	—	0.35
L1	0.20	0.30	0.25
L2	0.20	0.30	0.25
L3	—	—	0.40
z	0.02	0.08	0.05
All Dimensions in mm			

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

X2-DFN1006-3

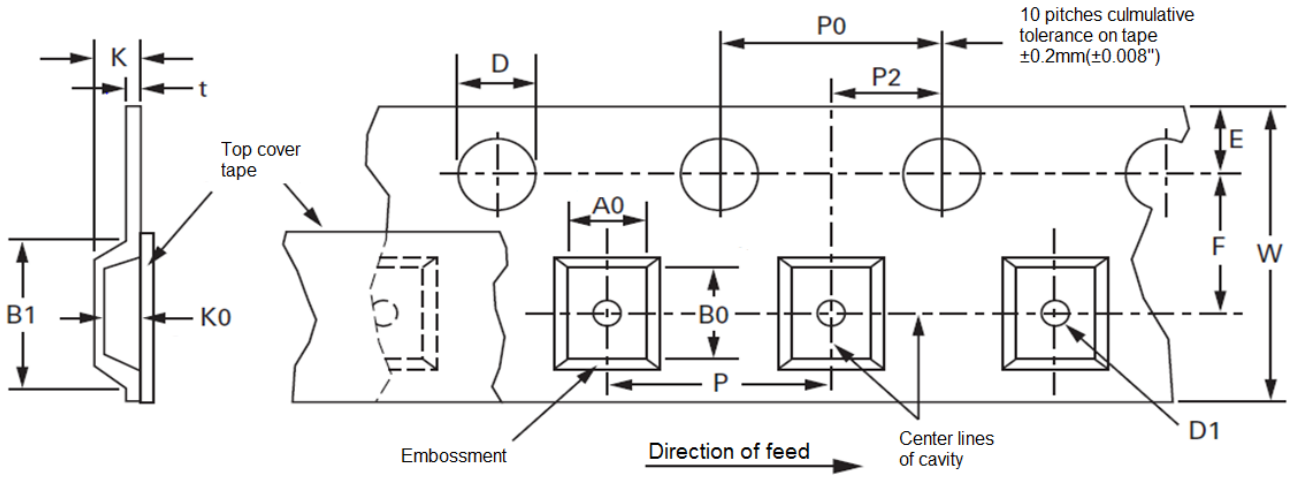


Dimensions	Value (in mm)
C	0.70
G1	0.30
G2	0.20
X	0.40
X1	1.10
Y	0.25
Y1	0.70

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Embossed Carrier Tape Specifications

Please see http://www.diodes.com/package-outlines.html for the latest version.



Tape Width (W)	Dimension	Value (mm)	Dimension	Value (mm)	Dimension	Value (mm)
8mm	**B1**	4.5 max.	**F**	3.5±0.05	**P2**	2.0±0.05
	D	1.5+0.10 -0.0	**K**	2.4 max.	**t**	0.40 max.
	D1	0.35 min.	**P**	4.0±0.10 2.0±0.05(-7B)	**W**	8±0.30
	E	1.75±0.10	**P0**	4.0±0.10		
	A0 B0 K0	Determined by component size. The clearance between the component and the cavity must comply to the rotational and lateral movement requirement provided in figures in the "Maximum Component Movement in Tape Pocket" section.				

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